

### FEATURES

- Good CTR Linearity Depending on Forward Current
- Isolation Test Voltage, 3000 V<sub>RMS</sub>
- High Collector-Emitter Voltage, V<sub>CEO</sub>=30 V
- Low Saturation Voltage
- Fast Switching Times
- Field-Effect Stable by TRIOS\*

### DESCRIPTION

The IL352 is an optically coupled isolator that features a high current transfer ratio, low coupling capacitance and high isolation voltage. It has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector. The component is housed in a thin line package.

The coupling device is designed for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled must not exceed the maximum permissible reference voltages.

### Maximum Ratings

#### Emitter

Reverse Voltage ..... 6.0 V  
 DC Forward Current ..... 60 mA  
 Total Power Dissipation ..... 50 mW  
 Derate Linearly from 25°C ..... 0.66 mW/°C

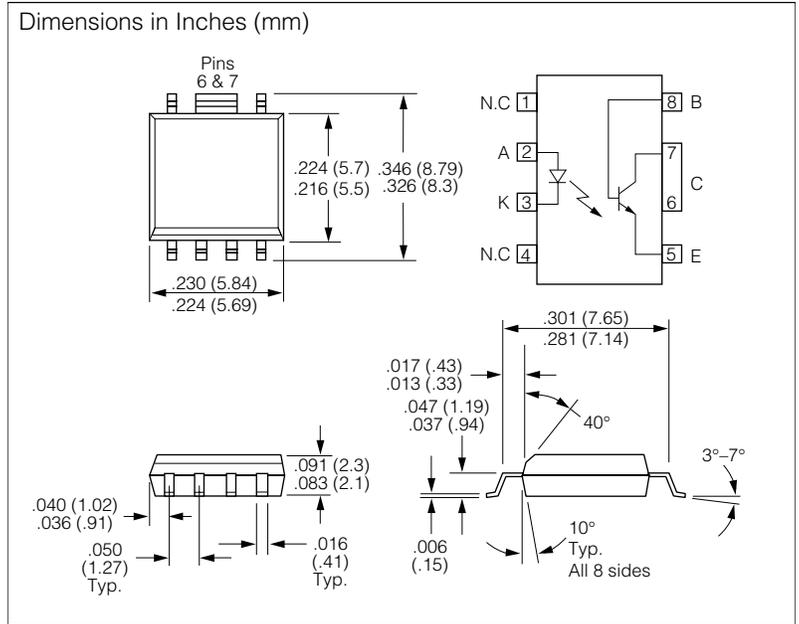
#### Detector

Collector-Emitter Voltage ..... 70 V  
 Emitter-Base Voltage ..... 7.0 V  
 Collector Current ..... 50 mA  
 Collector Current (t ≤ 1.0 ms) ..... 100 mA  
 Total Power Dissipation ..... 150 mW  
 Derate Linearly from 25°C ..... 2.5 mW/°C

#### Package

Isolation Test Voltage (between emitter and detector referred to climate DIN 40046, part 2, Nov. 74)  
 t = 1.0 sec ..... 3000 V<sub>RMS</sub>  
 Isolation Resistance  
 V<sub>IO</sub> = 500 V, T<sub>A</sub> = 25°C ..... ≥ 10<sup>12</sup> Ω  
 V<sub>IO</sub> = 500 V, T<sub>A</sub> = 100°C ..... ≥ 10<sup>11</sup> Ω  
 Storage Temperature Range ..... -40°C to +150°C  
 Ambient Temperature Range ..... -40°C to +85°C  
 Junction Temperature ..... 100°C  
 Soldering Temperature  
 (max 10 s, Dip Soldering Distance to Seating Plane ≥ 1.5 mm) ..... 260°C

\*TRansparent IO Shield



### Characteristics T<sub>A</sub>=25°C

Emitter	Sym.	Min.	Typ.	Max.	Units	Condition
Forward Voltage	V <sub>F</sub>	—	1.3	1.5	V	I <sub>F</sub> = 10 mA
Reverse Current	I <sub>R</sub>	—	0.1	10	μA	V <sub>R</sub> = 6.0 V
Capacitance	C <sub>O</sub>	—	25	—	pF	V <sub>R</sub> = 0 f = 1.0 MHz
<b>Detector</b>						
Breakdown Voltage Collector-Emitter Emitter-Collector	BV <sub>CEO</sub> BV <sub>ECO</sub>	30 7.0	—	—	V	I <sub>C</sub> = 1.0 mA I <sub>E</sub> = 100 μA
Collector-Emitter Leakage	I <sub>CEO</sub>	—	5.0	50	nA	V <sub>CE</sub> = 10 V I <sub>F</sub> = 0 T <sub>A</sub> = 25°C
		—	—	500	μA	V <sub>CE</sub> = 30 V I <sub>F</sub> = 0 T <sub>A</sub> = 85°C
Collector to Base	BV <sub>CBO</sub>	70	—	—	V	I <sub>C</sub> = 100 μA
Capacitance Collector-Emitter	C <sub>CE</sub>	—	6.0	—	pF	V <sub>CE</sub> = 0

Characteristics  $T_A=25^\circ\text{C}$  (continued)

Package	Symbol	Min.	Typ.	Max.	Units	Condition
DC Current Transfer Ratio	CTR	100	—	—	%	$I_F=10\text{ mA}$ $V_{CE}=10\text{ V}$
DC Current Transfer Ratio	CTR	34	—	—	%	$I_F=1.0\text{ mA}$ $V_{CE}=10\text{ V}$
Saturation Voltage Collector-Emitter	$V_{CEsat}$	—	—	0.3	V	$I_F=10\text{ mA}$ , $I_C=0.5\text{ mA}$
Coupling Capacitance	$C_{IO}$	—	0.5	—	pF	$f=1.0\text{ MHz}$
Switching Time, Non-Saturated	$t_{on}$ , $t_{off}$	—	10	—	$\mu\text{s}$	$I_C=2.0\text{ mA}$ $R_E=100\ \Omega$ $V_{CC}=10\text{ V}$ $RH\leq 50\%$

Figure 1. Switching waveform

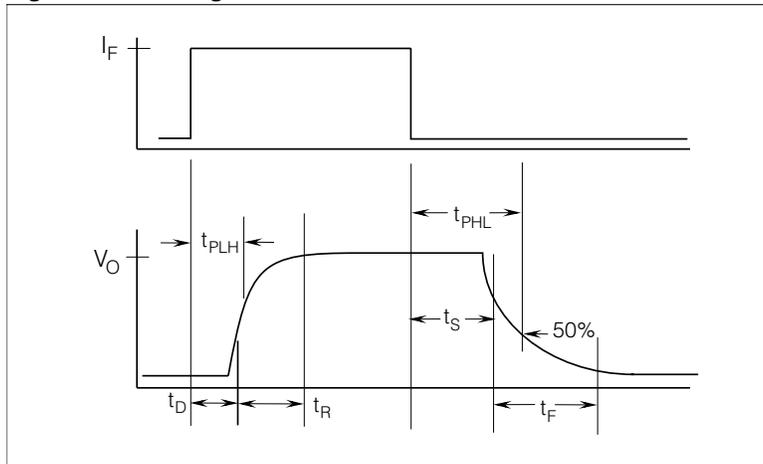


Figure 2. Switching schematic

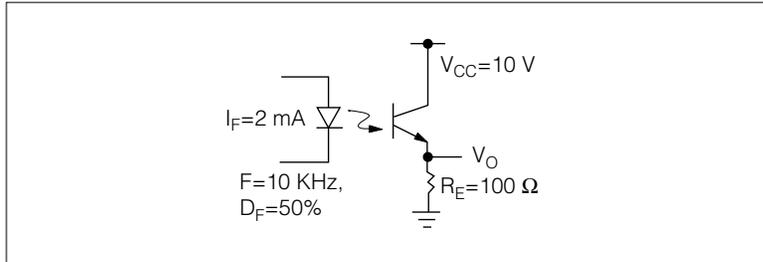


Figure 3. Forward voltage versus forward current

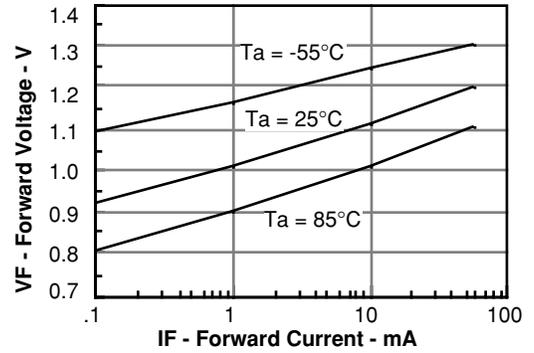


Figure 4. Normalized non-saturated and saturated CTR at  $T_A=25^\circ\text{C}$  versus LED current

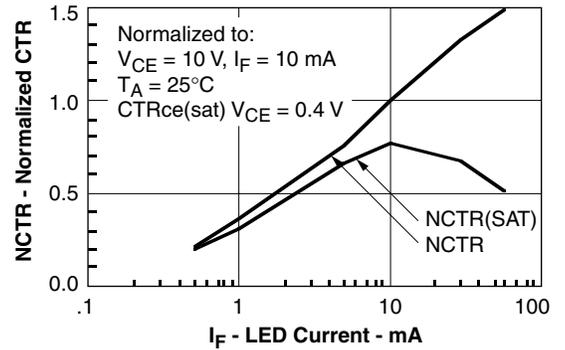


Figure 5. Normalized non-saturated and saturated CTR at  $T_A=50^\circ\text{C}$  versus LED current

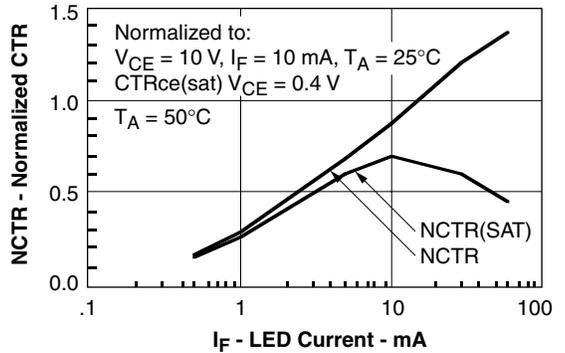


Figure 6. Normalized non-saturated and saturated CTR at  $T_A=70^\circ\text{C}$  versus LED current

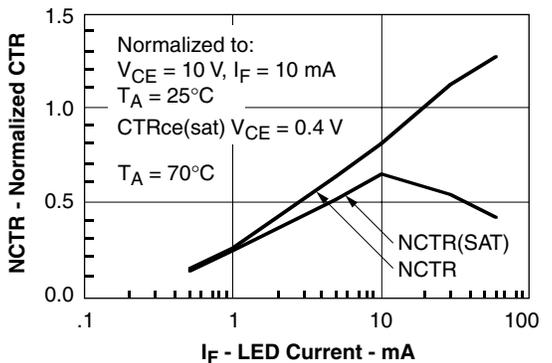


Figure 7. Normalized non-saturated and saturated CTR at  $T_A=85^\circ\text{C}$  versus LED current

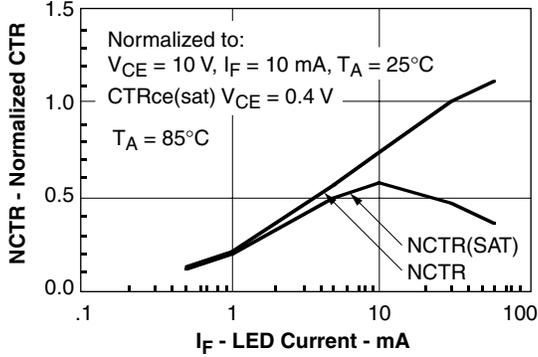


Figure 8. Collector-emitter current versus temperature and LED current

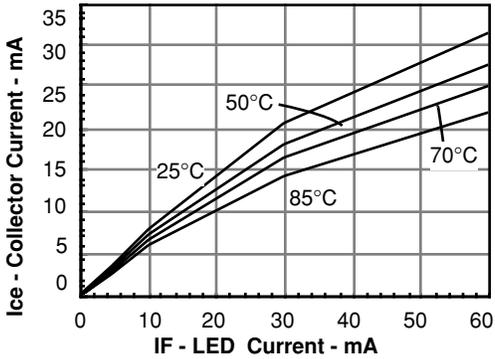


Figure 9. Collector-emitter leakage current versus temperature

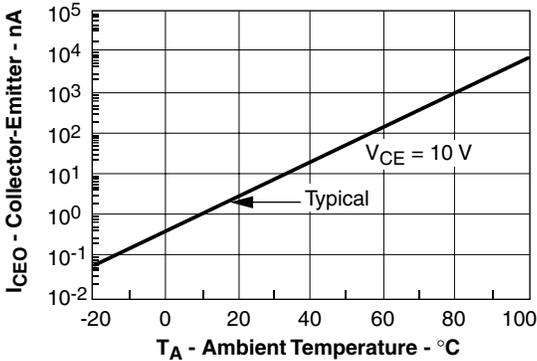


Figure 10. Normalized  $\text{CTR}_{cb}$  versus LED current and temperature

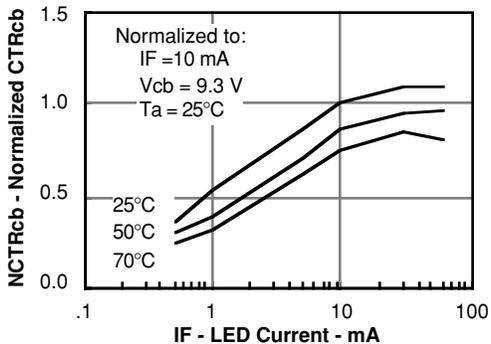


Figure 11. Collector base photocurrent versus LED current

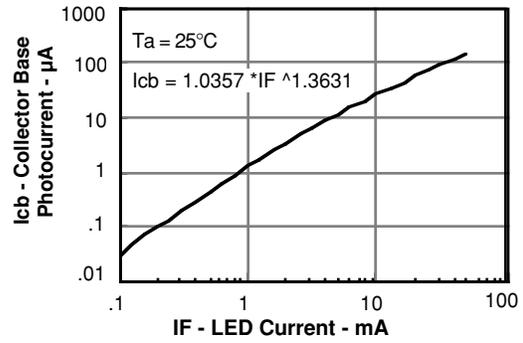


Figure 12. Normalized photocurrent versus  $I_F$  and temperature

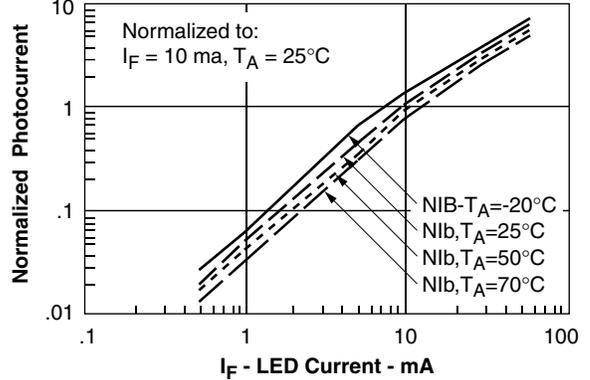


Figure 13. Propagation delay versus collector load resistor

